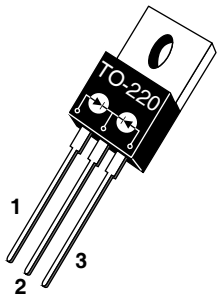


- 1 - Anode 1
- 2 - Common Cathode
Back of Case - Cathode
- 3 - Anode 2




**ADVANCED
POWER
TECHNOLOGY®**
APT8DQ60KCT 600V 2X8A

ULTRAFAST SOFT RECOVERY RECTIFIER DIODE

PRODUCT APPLICATIONS	PRODUCT FEATURES	PRODUCT BENEFITS
<ul style="list-style-type: none"> Parallel Diode <ul style="list-style-type: none"> -Switchmode Power Supply -Inverters Free Wheeling Diode <ul style="list-style-type: none"> -Motor Controllers -Converters Snubber Diode Uninterruptible Power Supply (UPS) Induction Heating High Speed Rectifiers 	<ul style="list-style-type: none"> Ultrafast Recovery Times Soft Recovery Characteristics Popular TO-220 Package Low Forward Voltage High Blocking Voltage Low Leakage Current 	<ul style="list-style-type: none"> Low Losses Low Noise Switching Cooler Operation Higher Reliability Systems Increased System Power Density

MAXIMUM RATINGS

All Ratings Per Leg: $T_C = 25^\circ\text{C}$ unless otherwise specified.

Symbol	Characteristic / Test Conditions	APT8DQ60KCT	UNIT
V_R	Maximum D.C. Reverse Voltage	600	Volts
V_{RRM}	Maximum Peak Repetitive Reverse Voltage		
V_{RWM}	Maximum Working Peak Reverse Voltage		
$I_{F(AV)}$	Maximum Average Forward Current ($T_C = 121^\circ\text{C}$, Duty Cycle = 0.5)	8	Amps
$I_{F(AV)}$	RMS Forward Current (Square wave, 50% duty)	14	
I_{FSM}	Non-Repetitive Forward Surge Current ($T_J = 45^\circ\text{C}$, 8.3ms)	110	
T_J, T_{STG}	Operating and Storage Temperature Range	-55 to 175	$^\circ\text{C}$
T_L	Lead Temperature for 10 Sec.	300	

STATIC ELECTRICAL CHARACTERISTICS

Symbol	Characteristic / Test Conditions	MIN	TYP	MAX	UNIT
V_F	Forward Voltage		$I_F = 8\text{A}$	2.0	2.4
			$I_F = 16\text{A}$	2.5	
			$I_F = 8\text{A}, T_J = 125^\circ\text{C}$	1.6	
I_{RM}	Maximum Reverse Leakage Current		$V_R = V_R \text{ Rated}$		150
			$V_R = V_R \text{ Rated}, T_J = 125^\circ\text{C}$		500
C_T	Junction Capacitance, $V_R = 200\text{V}$		15		pF

DYNAMIC CHARACTERISTICS

APT8DQ60KCT

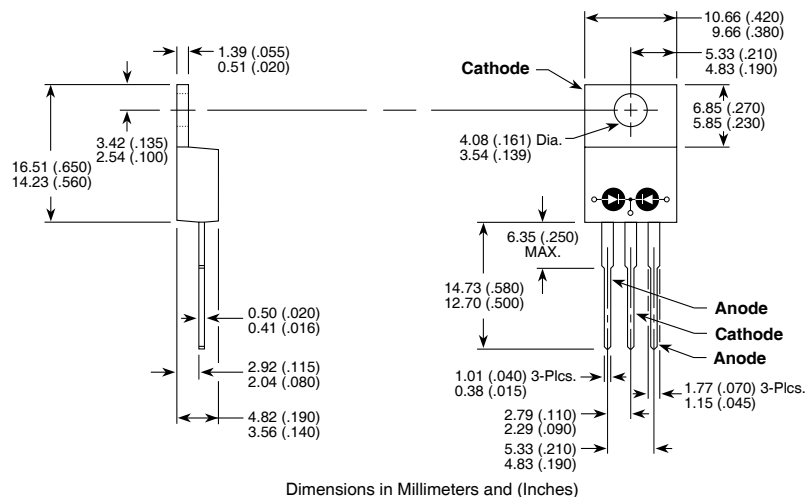
Symbol	Characteristic	Test Conditions	MIN	TYP	MAX	UNIT
t_{rr}	Reverse Recovery Time	$I_F = 1A, di_F/dt = -100A/\mu s, V_R = 30V, T_J = 25^\circ C$	-	15		ns
t_{rr}	Reverse Recovery Time	$I_F = 8A, di_F/dt = -200A/\mu s, V_R = 400V, T_C = 25^\circ C$	-	18		
Q_{rr}	Reverse Recovery Charge		-	20		nC
I_{RRM}	Maximum Reverse Recovery Current		-	1.8	-	Amps
t_{rr}	Reverse Recovery Time	$I_F = 8A, di_F/dt = -200A/\mu s, V_R = 400V, T_C = 125^\circ C$	-	85		ns
Q_{rr}	Reverse Recovery Charge		-	200		nC
I_{RRM}	Maximum Reverse Recovery Current		-	4	-	Amps
t_{rr}	Reverse Recovery Time	$I_F = 8A, di_F/dt = -1000A/\mu s, V_R = 400V, T_C = 125^\circ C$	-	45		ns
Q_{rr}	Reverse Recovery Charge		-	300		nC
I_{RRM}	Maximum Reverse Recovery Current		-	11		Amps

THERMAL AND MECHANICAL CHARACTERISTICS

Symbol	Characteristic / Test Conditions	MIN	TYP	MAX	UNIT
$R_{\theta JC}$	Junction-to-Case Thermal Resistance			2.70	$^\circ C/W$
$R_{\theta JA}$	Junction-to-Ambient Thermal Resistance			80	
W_T	Package Weight		0.07		oz
			1.2		g
Torque	Maximum Mounting Torque			10	lb•in
				1.1	N•m

APT Reserves the right to change, without notice, the specifications and information contained herein.

TO-220 (KCT) Package Outline



APT's products are covered by one or more of U.S. patents 4,895,810 5,045,903 5,089,434 5,182,234 5,019,522 5,262,336 6,503,786 5,256,583 4,748,103 5,283,202 5,231,474 5,434,095 5,528,058 and foreign patents. US and Foreign patents pending. All Rights Reserved.



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